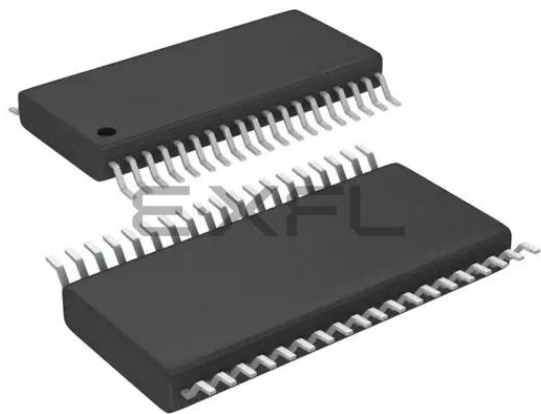




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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

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Details

Product Status	Active
Core Processor	ARM® Cortex®-M0
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I ² C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, I ² S, POR, PWM, WDT
Number of I/O	26
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 16x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	38-TFSOP (0.173", 4.40mm Width)
Supplier Device Package	PG-TSSOP-38-9
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/xmc1301t038f0064abxuma1

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- Configurable pad hysteresis

On-Chip Debug Support

- Support for debug features: 4 breakpoints, 2 watchpoints
- Various interfaces: ARM serial wire debug (SWD), single pin debug (SPD)

1.1 Ordering Information

The ordering code for an Infineon microcontroller provides an exact reference to a specific product. The code "XMC1<DDD>-<Z><PPP><T><FFFF>" identifies:

- <DDD> the derivatives function set
- <Z> the package variant
 - T: TSSOP
 - Q: VQFN
- <PPP> package pin count
- <T> the temperature range:
 - F: -40°C to 85°C
 - X: -40°C to 105°C
- <FFFF> the Flash memory size.

For ordering codes for the XMC1300 please contact your sales representative or local distributor.

This document describes several derivatives of the XMC1300 series, some descriptions may not apply to a specific product. Please see [Table 1](#).

For simplicity the term **XMC1300** is used for all derivatives throughout this document.

1.2 Device Types

These device types are available and can be ordered through Infineon's direct and/or distribution channels.

Table 1 Synopsis of XMC1300 Device Types

Derivative	Package	Flash Kbytes	SRAM Kbytes
XMC1301-T016F0008	PG-TSSOP-16-8	8	16
XMC1301-T016F0016	PG-TSSOP-16-8	16	16
XMC1301-T016F0032	PG-TSSOP-16-8	32	16
XMC1301-T016X0008	PG-TSSOP-16-8	8	16
XMC1301-T016X0016	PG-TSSOP-16-8	16	16
XMC1302-T016X0008	PG-TSSOP-16-8	8	16

Summary of Features
Table 1 Synopsis of XMC1300 Device Types (cont'd)

Derivative	Package	Flash Kbytes	SRAM Kbytes
XMC1302-T016X0016	PG-TSSOP-16-8	16	16
XMC1302-T016X0032	PG-TSSOP-16-8	32	16
XMC1302-T028X0016	PG-TSSOP-28-8	16	16
XMC1301-T038F0008	PG-TSSOP-38-9	8	16
XMC1301-T038F0016	PG-TSSOP-38-9	16	16
XMC1301-T038F0032	PG-TSSOP-38-9	32	16
XMC1301-T038X0032	PG-TSSOP-38-9	32	16
XMC1301-T038F0064	PG-TSSOP-38-9	64	16
XMC1302-T038X0016	PG-TSSOP-38-9	16	16
XMC1302-T038X0032	PG-TSSOP-38-9	32	16
XMC1302-T038X0064	PG-TSSOP-38-9	64	16
XMC1302-T038X0128	PG-TSSOP-38-9	128	16
XMC1302-T038X0200	PG-TSSOP-38-9	200	16
XMC1301-Q024F0008	PG-VQFN-24-19	8	16
XMC1301-Q024F0016	PG-VQFN-24-19	16	16
XMC1302-Q024F0016	PG-VQFN-24-19	16	16
XMC1302-Q024F0032	PG-VQFN-24-19	32	16
XMC1302-Q024F0064	PG-VQFN-24-19	64	16
XMC1302-Q024X0016	PG-VQFN-24-19	16	16
XMC1302-Q024X0032	PG-VQFN-24-19	32	16
XMC1302-Q024X0064	PG-VQFN-24-19	64	16
XMC1301-Q040F0008	PG-VQFN-40-13	8	16
XMC1301-Q040F0016	PG-VQFN-40-13	16	16
XMC1301-Q040F0032	PG-VQFN-40-13	32	16
XMC1302-Q040X0016	PG-VQFN-40-13	16	16
XMC1302-Q040X0032	PG-VQFN-40-13	32	16
XMC1302-Q040X0064	PG-VQFN-40-13	64	16
XMC1302-Q040X0128	PG-VQFN-40-13	128	16
XMC1302-Q040X0200	PG-VQFN-40-13	200	16

1.3 Device Type Features

The following table lists the available features per device type.

Table 2 Features of XMC1300 Device Types¹⁾

Derivative	ADC channel	ACMP	BCCU	MATH
XMC1301-T016	11	2	-	-
XMC1302-T016	11	2	1	1
XMC1302-T028	14	3	1	1
XMC1301-T038	16	3	-	-
XMC1302-T038	16	3	1	1
XMC1301-Q024	13	3	-	-
XMC1302-Q024	13	3	1	1
XMC1301-Q040	16	3	-	-
XMC1302-Q040	16	3	1	1

1) Features that are not included in this table are available in all the derivatives

Table 3 ADC Channels¹⁾

Package	VADC0 G0	VADC0 G1
PG-TSSOP-16	CH0..CH5	CH0..CH4
PG-TSSOP-28	CH0..CH7	CH0 .. CH4, CH7
PG-TSSOP-38	CH0..CH7	CH0..CH7
PG-VQFN-24	CH0..CH7	CH0..CH4
PG-VQFN-40	CH0..CH7	CH0..CH7

1) Some pins in a package may be connected to more than one channel. For the detailed mapping see the Port I/O Function table.

1.4 Chip Identification Number

The Chip Identification Number allows software to identify the marking. It is a 8 words value with the most significant 7 words stored in Flash configuration sector 0 (CS0) at address location : 1000 0F00_H (MSB) - 1000 0F1B_H (LSB). The least significant word and most significant word of the Chip Identification Number are the value of registers DBGROMID and IDCHIP, respectively.

Summary of Features

Table 4 XMC1300 Chip Identification Number (cont'd)

Derivative	Value	Marking
XMC1302-Q040X0128	00013043 01FF00FF 00001FF7 0000900F 00000C00 00001000 00021000 201ED083 _H	AB
XMC1302-Q040X0200	00013043 01FF00FF 00001FF7 0000900F 00000C00 00001000 00033000 201ED083 _H	AB

General Device Information
Table 6 Package Pin Mapping (cont'd)

Function	VQFN 40	TSSOP 38	TSSOP 28	VQFN 24	TSSOP 16	Pad Type	Notes
P0.7	30	24	17	18	10	STD_IN OUT	
P0.8	33	27	18	19	11	STD_IN OUT	
P0.9	34	28	19	20	12	STD_IN OUT	
P0.10	35	29	20	-	-	STD_IN OUT	
P0.11	36	30	-	-	-	STD_IN OUT	
P0.12	37	31	21	21	-	STD_IN OUT	
P0.13	38	32	22	22	-	STD_IN OUT	
P0.14	39	33	23	23	13	STD_IN OUT	
P0.15	40	34	24	24	14	STD_IN OUT	
P1.0	22	16	12	14	-	High Current	
P1.1	21	15	11	13	-	High Current	
P1.2	20	14	10	12	-	High Current	
P1.3	19	13	9	11	-	High Current	
P1.4	18	12	-	-	-	High Current	
P1.5	17	11	-	-	-	High Current	
P1.6	16	-	-	-	-	STD_IN OUT	
P2.0	1	35	25	1	15	STD_IN OUT/AN	

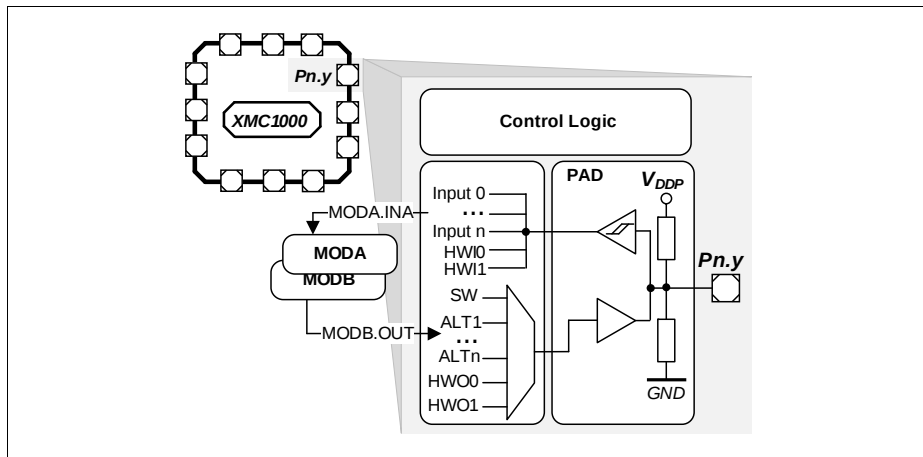


Figure 9 Simplified Port Structure

Pn.y is the port pin name, defining the control and data bits/registers associated with it. As GPIO, the port is under software control. Its input value is read via Pn_IN.y, Pn_OUT defines the output value.

Up to seven alternate output functions (ALT1/2/3/4/5/6/7) can be mapped to a single port pin, selected by Pn_IOC.R.PC. The output value is directly driven by the respective module, with the pin characteristics controlled by the port registers (within the limits of the connected pad).

The port pin input can be connected to multiple peripherals. Most peripherals have an input multiplexer to select between different possible input sources.

The input path is also active while the pin is configured as output. This allows to feedback an output to on-chip resources without wasting an additional external pin.

Please refer to the [Port I/O Functions](#) table for the complete Port I/O function mapping.

Table 9 Port I/O Functions

Function	Outputs							Inputs								
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	Input	Input	Input	Input	Input	Input	Input	Input	Input
P0.0	ERU0. PDOUT0		ERU0. GOUT0	CCU40. OUT0	CCU80. OUT00	USIC0_C H0.SELO 0	USIC0_C H1.SELO 0	BCCU0. TRAPINB	CCU40. IN0C			USIC0_C H0.DX2A	USIC0_C H1.DX2A			
P0.1	ERU0. PDOUT1		ERU0. GOUT1	CCU40. OUT1	CCU80. OUT01	BCCU0. OUT8	SCU. VDROP		CCU40. IN1C							
P0.2	ERU0. PDOUT2		ERU0. GOUT2	CCU40. OUT2	CCU80. OUT02	VADC0. EMUX02	CCU80. OUT10		CCU40. IN2C							
P0.3	ERU0. PDOUT3		ERU0. GOUT3	CCU40. OUT3	CCU80. OUT03	VADC0. EMUX01	CCU80. OUT11		CCU40. IN3C							
P0.4	BCCU0. OUT0			CCU40. OUT1	CCU80. OUT13	VADC0. EMUX00	WWDT. SERVICE _OUT		CCU80. IN0B							
P0.5	BCCU0. OUT1			CCU40. OUT0	CCU80. OUT12	ACMP2. OUT	CCU80. OUT01		CCU80. IN1B							
P0.6	BCCU0. OUT2			CCU40. OUT0	CCU80. OUT11	USIC0_C H1.MCLK OUT	USIC0_C H1.DOUT 0		CCU40. IN0B			USIC0_C H1.DX0C				
P0.7	BCCU0. OUT3			CCU40. OUT1	CCU80. OUT10	USIC0_C H0.SCLK OUT	USIC0_C H1.DOUT 0		CCU40. IN1B			USIC0_C H0.DX1C	USIC0_C H1.DX0D	USIC0_C H1.DX1C		
P0.8	BCCU0. OUT4			CCU40. OUT2	CCU80. OUT20	USIC0_C H0.SCLK OUT	USIC0_C H1.SCLK OUT		CCU40. IN2B			USIC0_C H0.DX1B	USIC0_C H1.DX1B			
P0.9	BCCU0. OUT5			CCU40. OUT3	CCU80. OUT21	USIC0_C H0.SELO 0	USIC0_C H1.SELO 0		CCU40. IN3B			USIC0_C H0.DX2B	USIC0_C H1.DX2B			
P0.10	BCCU0. OUT6			ACMP0. OUT	CCU80. OUT22	USIC0_C H0.SELO 1	USIC0_C H1.SELO 1		CCU80. IN2B			USIC0_C H0.DX2C	USIC0_C H1.DX2C			
P0.11	BCCU0. OUT7			USIC0_C H0.MCLK OUT	CCU80. OUT23	USIC0_C H0.SELO 2	USIC0_C H1.SELO 2					USIC0_C H0.DX2D	USIC0_C H1.DX2D			
P0.12	BCCU0. OUT6				CCU80. OUT33	USIC0_C H0.SELO 3	CCU80. OUT20	BCCU0. TRAPINA	CCU40. IN0A	CCU40. IN1A	CCU40. IN2A	CCU40. IN3A	CCU80. IN0A	CCU80. IN1A	CCU80. IN2A	USIC0_C H0.DX2E
P0.13	WWDT. SERVICE _OUT				CCU80. OUT32	USIC0_C H0.SELO 4	CCU80. OUT21		CCU80. IN3B	POSIF0. IN0B		USIC0_C H0.DX2F				

Table 9 Port I/O Functions (cont'd)

Function	Outputs							Inputs								
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	Input	Input	Input	Input	Input	Input	Input	Input	Input
P2.6								ACMP1.I NN	VADC0. G0CH0		ERU0.2A 1	USIC0_C H0.DX3E	USIC0_C H0.DX4E	USIC0_C H1.DX5D	ORC4.AI N	
P2.7								ACMP1.I NP	VADC0. G1CH1		ERU0.3A 1	USIC0_C H0.DX5C	USIC0_C H1.DX3D	USIC0_C H1.DX4D	ORC5.AI N	
P2.8								ACMP0.I NN	VADC0. G0CH1	VADC0. G1CH0	ERU0.3B 1	USIC0_C H0.DX3D	USIC0_C H0.DX4D	USIC0_C H1.DX5C	ORC6.AI N	
P2.9								ACMP0.I NP	VADC0. G0CH2	VADC0. G1CH4	ERU0.3B 0	USIC0_C H0.DX5A	USIC0_C H1.DX3B	USIC0_C H1.DX4B	ORC7.AI N	
P2.10	ERU0. PDOUT1	CCU40. OUT2	ERU0. GOUT1		CCU80. OUT30	ACMP0. OUT	USIC0_C H1.DOUT 0		VADC0. G0CH3	VADC0. G1CH2	ERU0.2B 0	USIC0_C H0.DX3C	USIC0_C H0.DX4C	USIC0_C H1.DX0F		
P2.11	ERU0. PDOUT0	CCU40. OUT3	ERU0. GOUT0		CCU80. OUT31	USIC0_C H1.SCLK OUT	USIC0_C H1.DOUT 0	ACMP.RE F	VADC0. G0CH4	VADC0. G1CH3	ERU0.2B 1	USIC0_C H1.DX0E	USIC0_C H1.DX1E			

Table 10 Hardware Controlled I/O Functions (cont'd)

Function	Outputs		Inputs		Pull Control			
	HWO0	HWO1	HWI0	HWI1	HW0_PD	HW0_PU	HW1_PD	HW1_PU
P2.6					BCCU0.OUT2	BCCU0.OUT2	CCU40.OUT3	CCU40.OUT3
P2.7					BCCU0.OUT8	BCCU0.OUT8	CCU40.OUT3	CCU40.OUT3
P2.8					BCCU0.OUT1	BCCU0.OUT1	CCU40.OUT2	CCU40.OUT2
P2.9					BCCU0.OUT7	BCCU0.OUT7	CCU40.OUT2	CCU40.OUT2
P2.10					BCCU0.OUT4	BCCU0.OUT4		
P2.11					BCCU0.OUT5	BCCU0.OUT5		

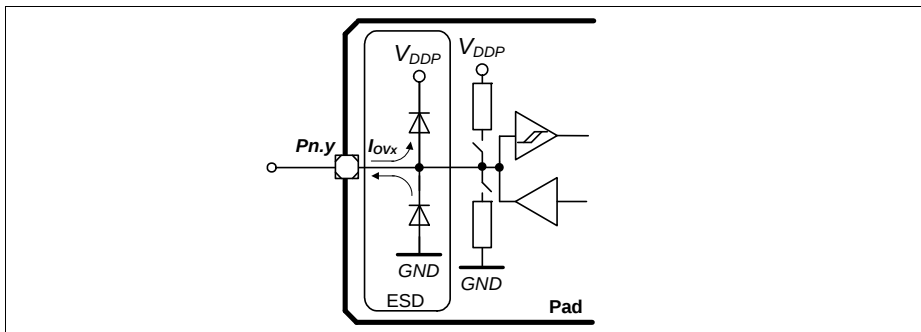


Figure 10 Input Overload Current via ESD structures

Table 13 and **Table 14** list input voltages that can be reached under overload conditions. Note that the absolute maximum input voltages as defined in the **Absolute Maximum Ratings** must not be exceeded during overload.

Table 13 PN-Junction Characteristics for positive Overload

Pad Type	$I_{OV} = 5 \text{ mA}$
Standard, High-current, AN/DIG_IN	$V_{IN} = V_{DDP} + 0.5 \text{ V}$ $V_{AIN} = V_{DDP} + 0.5 \text{ V}$ $V_{AREF} = V_{DDP} + 0.5 \text{ V}$
P2.[1,2,6:9,11]	$V_{INP2} = V_{DDP} + 0.3 \text{ V}$

Table 14 PN-Junction Characteristics for negative Overload

Pad Type	$I_{OV} = 5 \text{ mA}$
Standard, High-current, AN/DIG_IN	$V_{IN} = V_{SS} - 0.5 \text{ V}$ $V_{AIN} = V_{SS} - 0.5 \text{ V}$ $V_{AREF} = V_{SS} - 0.5 \text{ V}$
P2.[1,2,6:9,11]	$V_{INP2} = V_{SS} - 0.3 \text{ V}$

Electrical Parameters
Table 16 Input/Output Characteristics (Operating Conditions apply) (cont'd)

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
Input Hysteresis ⁸⁾	HYS	CC	$0.08 \times V_{DDP}$	—	V	CMOS Mode (5 V), Standard Hysteresis
			$0.03 \times V_{DDP}$	—	V	CMOS Mode (3.3 V), Standard Hysteresis
			$0.02 \times V_{DDP}$	—	V	CMOS Mode (2.2 V), Standard Hysteresis
			$0.5 \times V_{DDP}$	$0.75 \times V_{DDP}$	V	CMOS Mode(5 V), Large Hysteresis
			$0.4 \times V_{DDP}$	$0.75 \times V_{DDP}$	V	CMOS Mode(3.3 V), Large Hysteresis
			$0.2 \times V_{DDP}$	$0.65 \times V_{DDP}$	V	CMOS Mode(2.2 V), Large Hysteresis
Pin capacitance (digital inputs/outputs)	C_{IO}	CC	—	10	pF	
Pull-up resistor on port pins	R_{PUP}	CC	20	50	kohm	$V_{IN} = V_{SSP}$
Pull-down resistor on port pins	R_{PDP}	CC	20	50	kohm	$V_{IN} = V_{DDP}$
Input leakage current ⁹⁾	I_{OZP}	CC	-1	1	μA	$0 < V_{IN} < V_{DDP}$, $T_A \leq 105^\circ\text{C}$
Voltage on any pin during V_{DDP} power off	V_{PO}	SR	—	0.3	V	¹⁰⁾
Maximum current per pin (excluding P1, V_{DDP} and V_{SS})	I_{MP}	SR	-10	11	mA	—
Maximum current per high current pins	I_{MP1A}	SR	-10	50	mA	—
Maximum current into V_{DDP} (TSSOP16, VQFN24)	I_{MVDD1}	SR	—	130	mA	¹⁸⁾
Maximum current into V_{DDP} (TSSOP38, VQFN40)	I_{MVDD2}	SR	—	260	mA	¹⁸⁾

3.2.6 Power Supply Current

The total power supply current defined below consists of a leakage and a switching component.

Application relevant values are typically lower than those given in the following tables, and depend on the customer's system operating conditions (e.g. thermal connection or used application configurations).

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 21 Power Supply Parameters; $V_{DDP} = 5V$

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min	Typ. ¹⁾	Max.		
Active mode current Peripherals enabled f_{MCLK} / f_{PCLK} in MHz ²⁾	I_{DDPAE} CC	–	9.2	12	mA	32 / 64
		–	8.1	-	mA	24 / 48
		–	6.6	-	mA	16 / 32
		–	5.5	-	mA	8 / 16
		–	4	-	mA	1 / 1
Active mode current Peripherals disabled f_{MCLK} / f_{PCLK} in MHz ³⁾	I_{DDPAD} CC	–	4.8	-	mA	32 / 64
		–	4.1	-	mA	24 / 48
		–	3.3	-	mA	16 / 32
		–	2.7	-	mA	8 / 16
		–	1.5	-	mA	1 / 1
Active mode current Code execution from RAM Flash is powered down f_{MCLK} / f_{PCLK} in MHz	I_{DDPAR} CC	–	7.3	-	mA	32 / 64
		–	6.3	-	mA	24 / 48
		–	5.2	-	mA	16 / 32
		–	4.2	-	mA	8 / 16
		–	3.3	-	mA	1 / 1
Sleep mode current Peripherals clock enabled f_{MCLK} / f_{PCLK} in MHz ⁴⁾	I_{DDPSE} CC	–	6.6	-	mA	32 / 64
			5.8	-	mA	24 / 48
			5.1	-	mA	16 / 32
			4.4	-	mA	8 / 16
			3.7	-	mA	1 / 1

Electrical Parameters

Figure 14 shows typical graphs for active mode supply current for $V_{DDP} = 5V$, $V_{DDP} = 3.3V$, $V_{DDP} = 1.8V$ across different clock frequencies.

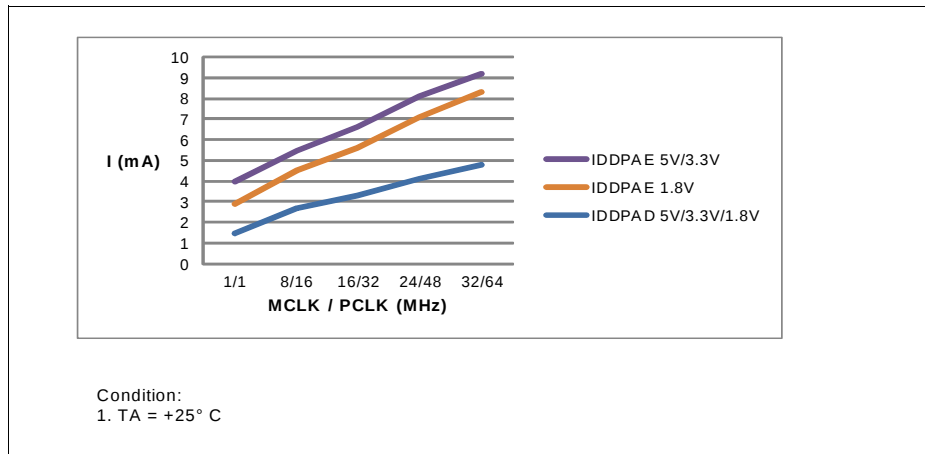


Figure 14 Active mode, a) peripherals clocks enabled, b) peripherals clocks disabled: Supply current I_{DDPA} over supply voltage V_{DDP} for different clock frequencies

3.2.7 Flash Memory Parameters

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 23 Flash Memory Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Erase Time per page / sector	$t_{\text{ERASE CC}}$	6.8	7.1	7.6	ms	
Program time per block	$t_{\text{PSER CC}}$	102	152	204	μs	
Wake-Up time	$t_{\text{WU CC}}$	–	32.2	–	μs	
Read time per word	$t_{\text{a CC}}$	–	50	–	ns	
Data Retention Time	$t_{\text{RET CC}}$	10	–	–	years	Max. 100 erase / program cycles
Flash Wait States ¹⁾	$N_{\text{WSFLASH CC}}$	0	0	0		$f_{\text{MCLK}} = 8 \text{ MHz}$
		0	1	1		$f_{\text{MCLK}} = 16 \text{ MHz}$
		1	1.3	2		$f_{\text{MCLK}} = 32 \text{ MHz}$
Fixed Flash Wait States configured in bit NVM_NVMCONF.WS	$N_{\text{FWSFLASH SR}}$	0	0	1		NVM_CONFIG1.FI XWS = 1 _B , $f_{\text{MCLK}} \leq 16 \text{ MHz}$
		1	1	1		NVM_CONFIG1.FI XWS = 1 _B , $16 \text{ MHz} < f_{\text{MCLK}} \leq 32 \text{ MHz}$
Erase Cycles	$N_{\text{ECCY CC}}$	–	–	$5 \cdot 10^4$	cycles	Sum of page and sector erase cycles
Total Erase Cycles	$N_{\text{TECCY CC}}$	–	–	$2 \cdot 10^6$	cycles	

1) Flash wait states are automatically inserted by the Flash module during memory read when needed. Typical values are calculated from the execution of the Dhrystone benchmark program.

3.3.5 SPD Timing Requirements

The optimum SPD decision time between 0_B and 1_B is $0.75 \mu s$. With this value the system has maximum robustness against frequency deviations of the sampling clock on tool and on device side. However it is not always possible to exactly match this value with the given constraints for the sample clock. For instance for a oversampling rate of 4, the sample clock will be 8 MHz and in this case the closest possible effective decision time is 5.5 clock cycles ($0.69 \mu s$).

Table 28 Optimum Number of Sample Clocks for SPD

Sample Freq.	Sampling Factor	Sample Clocks 0_B	Sample Clocks 1_B	Effective Decision Time ¹⁾	Remark
8 MHz	4	1 to 5	6 to 12	$0.69 \mu s$	The other closest option ($0.81 \mu s$) for the effective decision time is less robust.

1) Nominal sample frequency period multiplied with $0.5 + (\text{max. number of } 0_B \text{ sample clocks})$

For a balanced distribution of the timing robustness of SPD between tool and device, the timing requirements for the tool are:

- Frequency deviation of the sample clock is $\pm 5\%$
- Effective decision time is between $0.69 \mu s$ and $0.75 \mu s$ (calculated with nominal sample frequency)

Table 30 USIC SSC Slave Mode Timing

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
DX1 slave clock period	t_{CLK}	SR	125	–	–	ns	
Select input DX2 setup to first clock input DX1 transmit edge ¹⁾	t_{10}	SR	10	–	–	ns	
Select input DX2 hold after last clock input DX1 receive edge ¹⁾	t_{11}	SR	10	–	–	ns	
Receive data input DX0/DX[5:3] setup time to shift clock receive edge ¹⁾	t_{12}	SR	10	–	–	ns	
Data input DX0/DX[5:3] hold time from clock input DX1 receive edge ¹⁾	t_{13}	SR	10	–	–	ns	
Data output DOUT[3:0] valid time	t_{14}	CC	-	–	80	ns	

1) These input timings are valid for asynchronous input signal handling of slave select input, shift clock input, and receive data input (bits DXnCR.DSEN = 0).

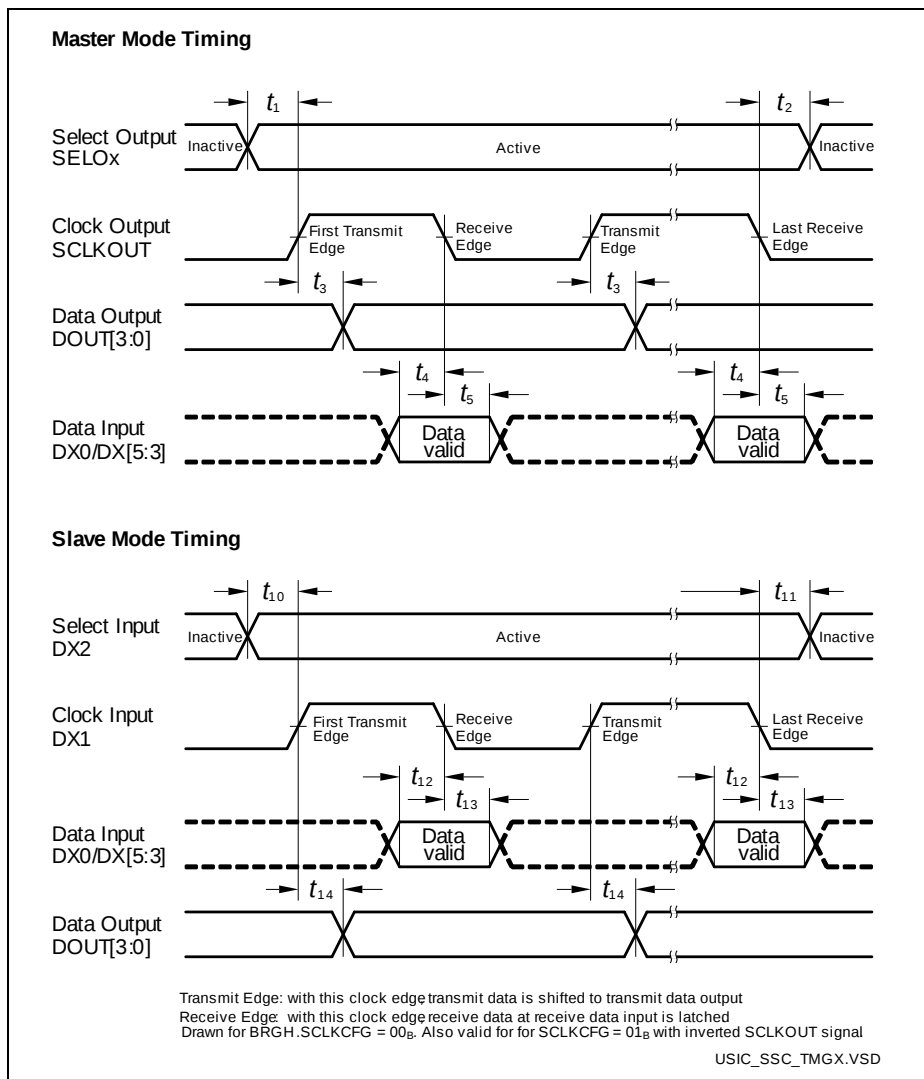


Figure 22 USIC - SSC Master/Slave Mode Timing

Note: This timing diagram shows a standard configuration, for which the slave select signal is low-active, and the serial clock signal is not shifted and not inverted.

Table 32 USIC IIC Fast Mode Timing¹⁾

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Fall time of both SDA and SCL	t_1 CC/SR	20 + 0.1 * C _b 2)	-	300	ns	
Rise time of both SDA and SCL	t_2 CC/SR	20 + 0.1 * C _b	-	300	ns	
Data hold time	t_3 CC/SR	0	-	-	µs	
Data set-up time	t_4 CC/SR	100	-	-	ns	
LOW period of SCL clock	t_5 CC/SR	1.3	-	-	µs	
HIGH period of SCL clock	t_6 CC/SR	0.6	-	-	µs	
Hold time for (repeated) START condition	t_7 CC/SR	0.6	-	-	µs	
Set-up time for repeated START condition	t_8 CC/SR	0.6	-	-	µs	
Set-up time for STOP condition	t_9 CC/SR	0.6	-	-	µs	
Bus free time between a STOP and START condition	t_{10} CC/SR	1.3	-	-	µs	
Capacitive load for each bus line	C _b SR	-	-	400	pF	

1) Due to the wired-AND configuration of an IIC bus system, the port drivers of the SCL and SDA signal lines need to operate in open-drain mode. The high level on these lines must be held by an external pull-up device, approximately 10 kOhm for operation at 100 kbit/s, approximately 2 kOhm for operation at 400 kbit/s.

2) C_b refers to the total capacitance of one bus line in pF.

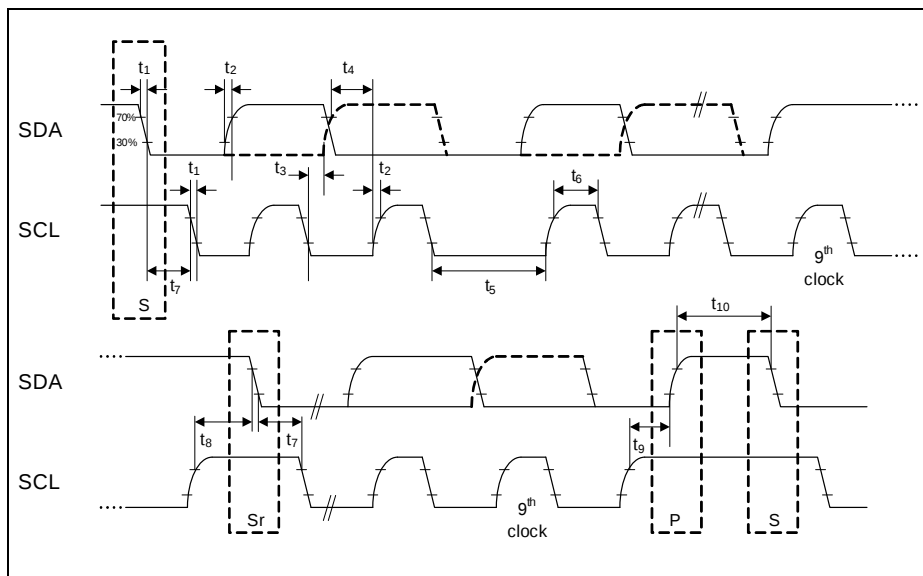


Figure 23 USIC IIC Stand and Fast Mode Timing

3.3.6.3 Inter-IC Sound (IIS) Interface Timing

The following parameters are applicable for a USIC channel operated in IIS mode.

Note: Operating Conditions apply.

Table 33 USIC IIS Master Transmitter Timing

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clock period	t_1 CC	$2/f_{MCLK}$	-	-	ns	$V_{DDP} \geq 3\text{ V}$
		$4/f_{MCLK}$	-	-	ns	$V_{DDP} < 3\text{ V}$
Clock HIGH	t_2 CC	$0.35 \times t_{1min}$	-	-	ns	
Clock Low	t_3 CC	$0.35 \times t_{1min}$	-	-	ns	
Hold time	t_4 CC	0	-	-	ns	
Clock rise time	t_5 CC	-	-	$0.15 \times t_{1min}$	ns	